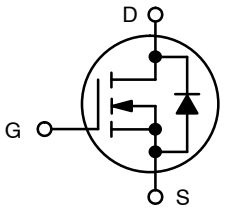
MOSFET – Power, N-Channel
100 V, 17 A, 81 mΩ

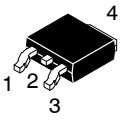
NTD6416AN, NVD6416AN

$V_{(BR)DSS}$	$R_{DS(on)}$ MAX	I_D MAX (Note 1)
100 V	81 mΩ @ 10 V	17 A

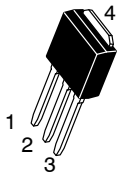


Features

- Low $R_{DS(on)}$
- High Current Capability
- 100% Avalanche Tested
- HBM ESD Level Class 1B, MM ESD Level Class M2
- NVD Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q101 Qualified and PPAP Capable
- These Devices are Pb−Free and are RoHS Compliant



DPAK
CASE 369AA
STYLE 2



IPAK
CASE 369D
STYLE 2

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Parameter			Symbol	Value	Unit
Drain−to−Source Voltage			V_{DSS}	100	V
Gate−to−Source Voltage − Continuous			V_{GS}	±20	V
Continuous Drain Current	Steady State	T_C = 25°C	I_D	17	A
		T_C = 100°C		11	
Power Dissipation	Steady State	T_C = 25°C	P_D	71	W
Pulsed Drain Current	t_p = 10 μs		I_{DM}	62	A
Operating and Storage Temperature Range			T_J, T_{stg}	−55 to +175	°C
Source Current (Body Diode)			I_S	17	A
Single Pulse Drain−to−Source Avalanche Energy (V_{DD} = 50 Vdc, V_{GS} = 10 Vdc, $I_{L(pk)}$ = 17 A, L = 0.3 mH, R_G = 25 Ω)			E_{AS}	43	mJ
Lead Temperature for Soldering Purposes, 1/8″ from Case for 10 Seconds			T_L	260	°C

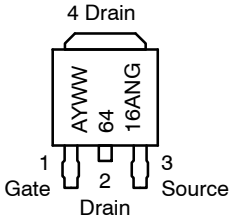
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

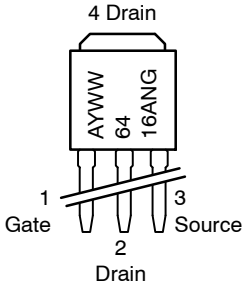
THERMAL RESISTANCE RATINGS

Parameter	Symbol	Max	Unit
Junction−to−Case (Drain) Steady State	$R_{\theta JC}$	2.1	°C/W
Junction−to−Ambient (Note 1)	$R_{\theta JA}$	40	

1. Surface mounted on FR4 board using 1 sq in pad size, (Cu Area 1.127 sq in [2 oz] including traces).

MARKING DIAGRAM & PIN ASSIGNMENTS





A	= Assembly Location*
Y	= Year
WW	= Work Week
6416AN	= Device Code
G	= Pb−Free Package

* The Assembly Location code (A) is front side optional. In cases where the Assembly Location is stamped in the package, the front side assembly code may be blank.

ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 5.

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ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Parameter	Symbol	Test Condition		Min	Typ	Max	Unit
OFF CHARACTERISTICS							
Drain−to−Source Breakdown Voltage	$V_{(BR)DSS}$	V_{GS} = 0 V, I_D = 250 μA		100			V
Drain−to−Source Breakdown Voltage Temperature Coefficient	$V_{(BR)DSS}/T_J$				112		mV/°C
Zero Gate Voltage Drain Current	I_{DSS}	V_{GS} = 0 V, V_{DS} = 100 V	T_J = 25°C			1.0	μA
			T_J = 125°C			10	
Gate−to−Source Leakage Current	I_{GSS}	V_{DS} = 0 V, V_{GS} = ±20 V				±100	nA
ON CHARACTERISTICS (Note 3)							
Gate Threshold Voltage	$V_{GS(TH)}$	V_{GS} = V_{DS}, I_D = 250 μA		2.0		4.0	V
Negative Threshold Temperature Coefficient	$V_{GS(TH)}/T_J$				7.7		mV/°C
Drain−to−Source On−Resistance	$R_{DS(on)}$	V_{GS} = 10 V, I_D = 17 A			73	81	mΩ
Forward Transconductance	g_{FS}	V_{DS} = 5 V, I_D = 10 A			12		S
CHARGES, CAPACITANCES AND GATE RESISTANCE							
Input Capacitance	C_{ISS}	V_{GS} = 0 V, f = 1.0 MHz, V_{DS} = 25 V			620		pF
Output Capacitance	C_{OSS}				110		
Reverse Transfer Capacitance	C_{RSS}				50		
Total Gate Charge	$Q_{G(TOT)}$	V_{GS} = 10 V, V_{DS} = 80 V, I_D = 17 A			20		nC
Threshold Gate Charge	$Q_{G(TH)}$				1.0		
Gate−to−Source Charge	Q_{GS}				3.6		
Gate−to−Drain Charge	Q_{GD}				10		
Plateau Voltage	V_{GP}				5.8		V
Gate Resistance	R_G				2.4		Ω
SWITCHING CHARACTERISTICS (Note 4)							
Turn−On Delay Time	$t_{d(on)}$	V_{GS} = 10 V, V_{DD} = 80 V, I_D = 17 A, R_G = 6.1 Ω			9.2		ns
Rise Time	t_r				22		
Turn−Off Delay Time	$t_{d(off)}$				24		
Fall Time	t_f				20		
DRAIN−SOURCE DIODE CHARACTERISTICS							
Forward Diode Voltage	V_{SD}	V_{GS} = 0 V, I_S = 17 A	T_J = 25°C		0.85	1.2	V
			T_J = 125°C		0.7		
Reverse Recovery Time	t_{rr}	V_{GS} = 0 V, dI_S/dt = 100 A/μs, I_S = 17 A			56		ns
Charge Time	t_a				41		
Discharge Time	t_b				15		
Reverse Recovery Charge	Q_{RR}				135		nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Surface mounted on FR4 board using 1 in sq pad size (Cu area = 1.127 in sq [1 oz] including traces).
3. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.
4. Switching characteristics are independent of operating junction temperatures.
5. ESD between the gate and source serves only, no gate overvoltage rating is implied.

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TYPICAL CHARACTERISTICS

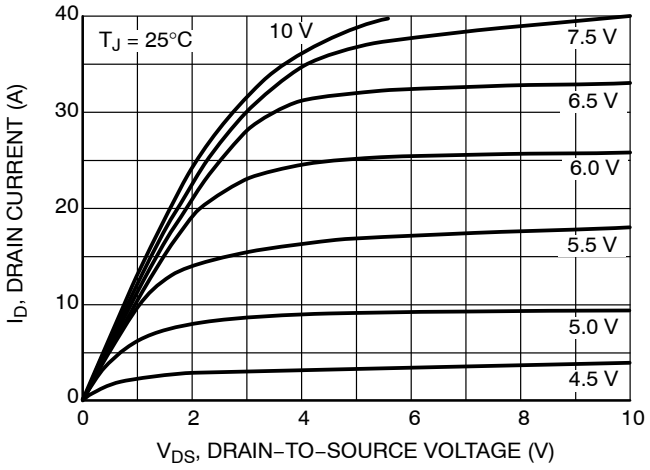

Figure 1. On−Region Characteristics

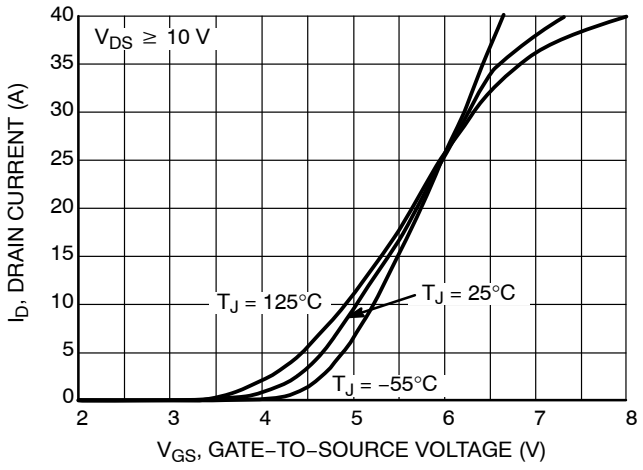

Figure 2. Transfer Characteristics

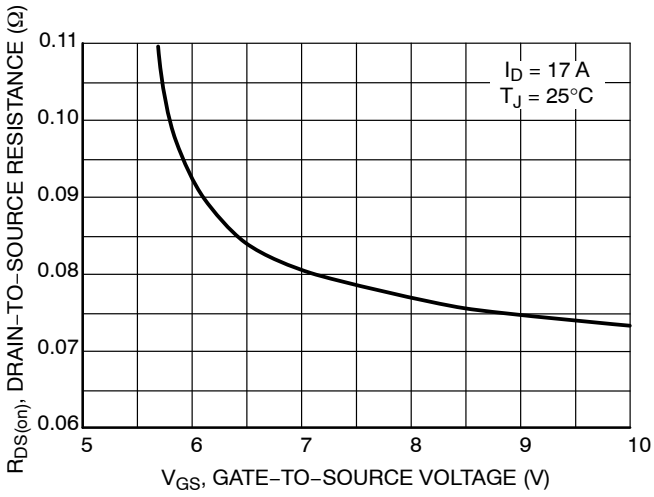

Figure 3. On−Region versus Gate Voltage

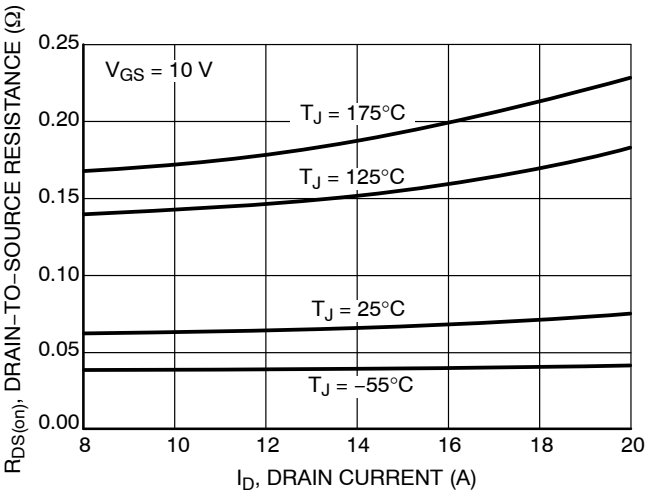

Figure 4. On−Resistance versus Drain Current and Gate Voltage

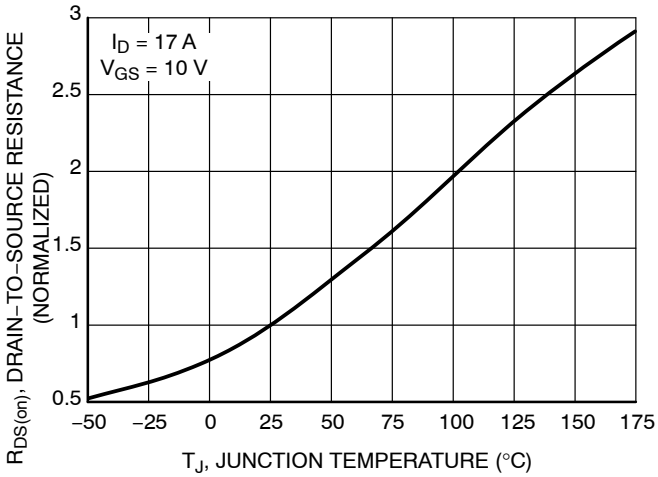

Figure 5. On−Resistance Variation with Temperature

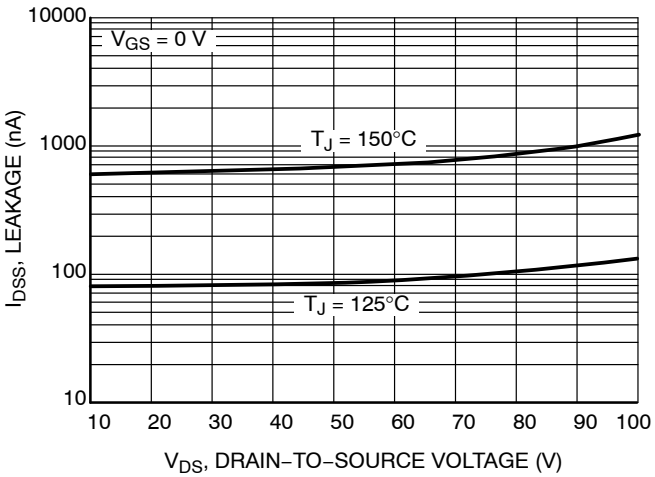

Figure 6. Drain−to−Source Leakage Current versus Voltage

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TYPICAL CHARACTERISTICS

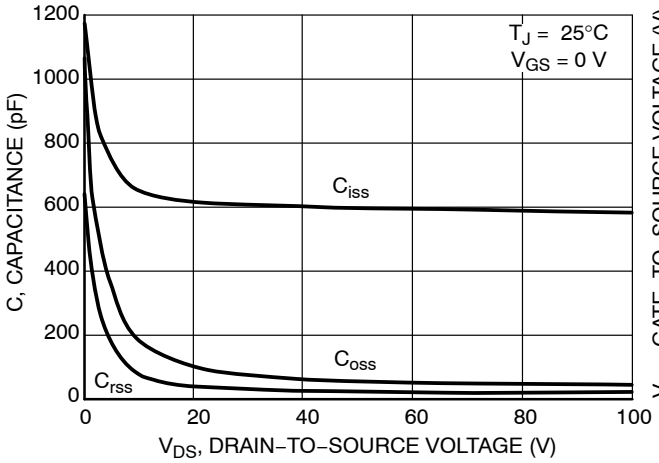

Figure 7. Capacitance Variation

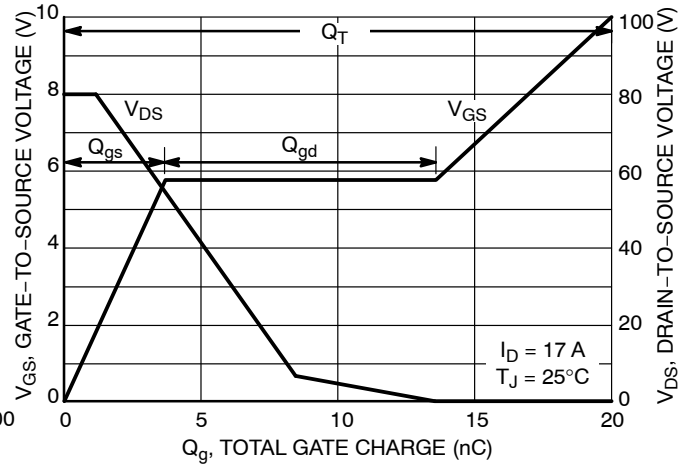

Figure 8. Gate−to−Source Voltage and Drain−to−Source Voltage versus Total Charge

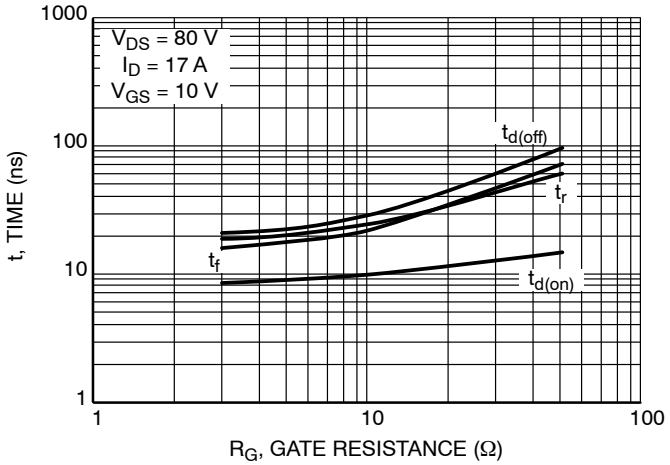

Figure 9. Resistive Switching Time Variation versus Gate Resistance

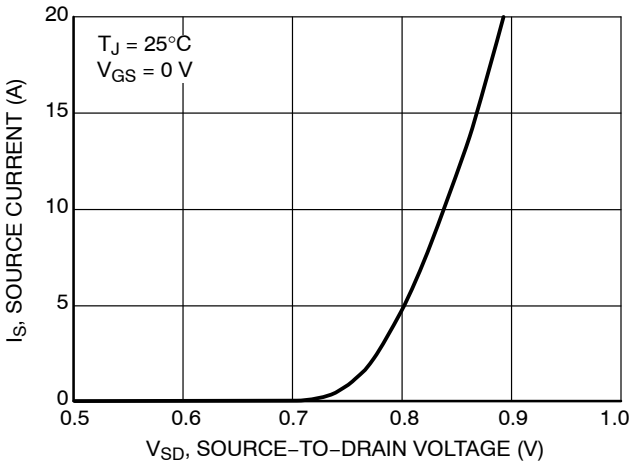

Figure 10. Diode Forward Voltage versus Current

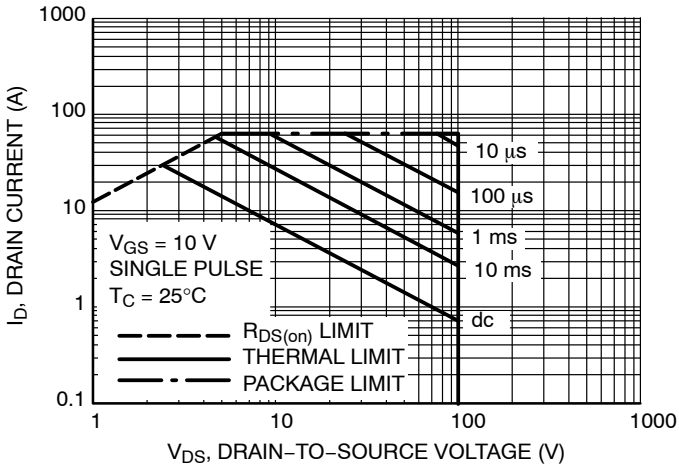

Figure 11. Maximum Rated Forward Biased Safe Operating Area

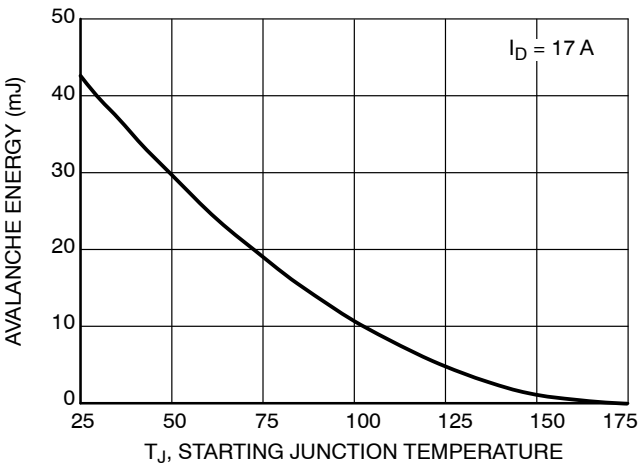

Figure 12. Maximum Avalanche Energy versus Starting Junction Temperature

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TYPICAL CHARACTERISTICS

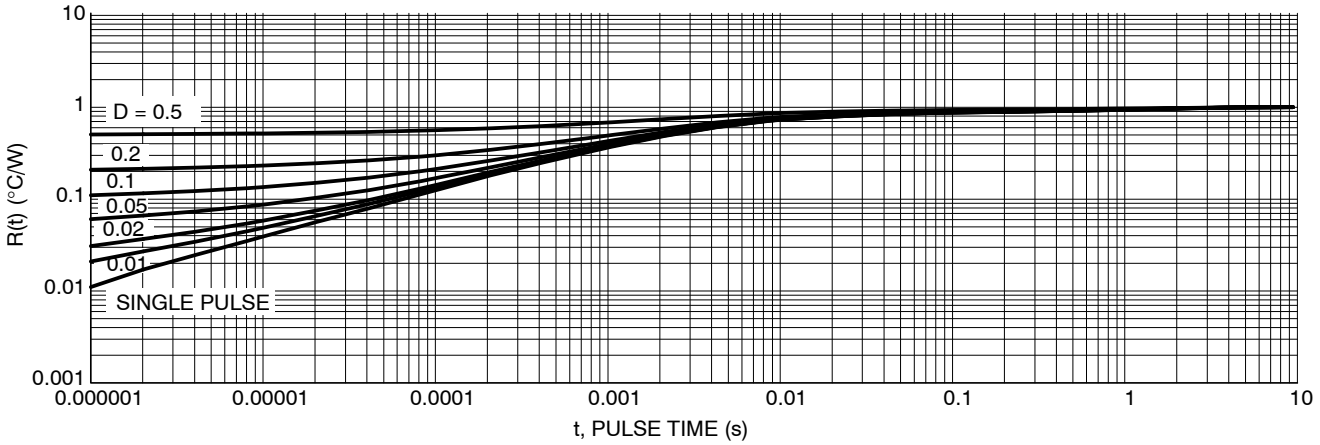

Figure 13. Thermal Response

ORDERING INFORMATION

Device	Package	Shipping†
NTD6416ANT4G	DPAK (Pb−Free)	2500 / Tape & Reel

DISCONTINUED (Note 6)

NTD6416AN−1G	IPAK (Pb−Free)	75 Units / Rail
NVD6416ANT4G*	DPAK (Pb−Free)	2500 / Tape & Reel
NVD6416ANT4G−VF01*	DPAK (Pb−Free)	2500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

*NVD Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q101 Qualified and PPAP Capable.

6. **DISCONTINUED:** These devices are not recommended for new design. Please contact your **onsemi** representative for information. The most current information on these devices may be available on www.onsemi.com.

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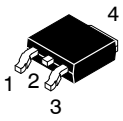


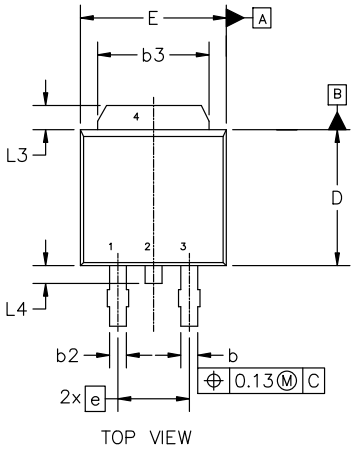
SCALE 1:1

DPAK−3 6.10x6.54x2.28, 2.29P
CASE 369AA
ISSUE C

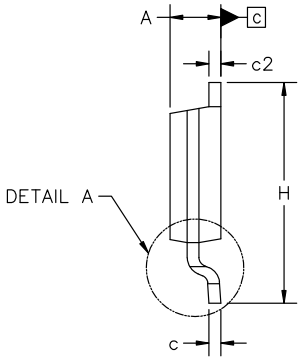
DATE 14 MAY 2026

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	2.18	2.28	2.38
A1	0.00	−−−	0.13
b	0.63	0.76	0.89
b2	0.76	0.95	1.14
b3	4.57	5.02	5.46
c	0.46	0.54	0.61
c2	0.46	0.54	0.61
D	5.97	6.10	6.22
E	6.35	6.54	6.73
e	2.29 BSC		
H	9.40	9.91	10.41
L	1.40	1.59	1.78
L1	2.74 REF		
L2	0.51 BSC		
L3	0.89	−−−	1.27
L4	−−−	−−−	1.01
Z	3.93	−−−	−−−

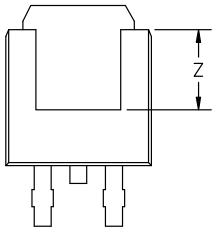
NOTES
1. DIMENSION AND TOLERANCING PER ASME Y14.5 2018
2. CONTROLLING DIMENSION: MILLIMETERS
3. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSION b3, L3, AND Z
4. DIMENSION D AND E DO NOT INCLUDED MOLD FLASH, PROTRUSION, OR BURRS.
5. DIMENSION D AND E ARE DETERMINED AT OUTERMOST EXTREMES OF THE PLASTIC BODY.
6. DATUMS A AND B ARE DETERMINED AT DATUM PLANE H



TOP VIEW

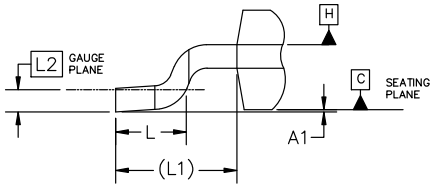


SIDE VIEW

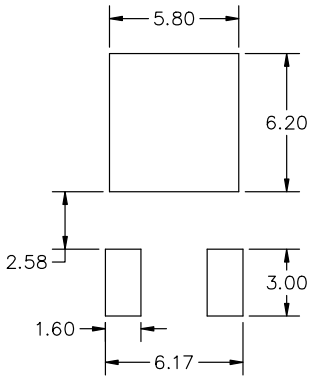


TOP VIEW

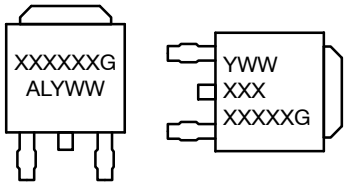
RECOMMENDED
MOUNTING FOOTPRINT



DETAIL A
ROTATED 90° CW



GENERIC
MARKING DIAGRAM*



IC **Discrete**

XXXXXX	= Device Code
A	= Assembly Location
L	= Wafer Lot
Y	= Year
WW	= Work Week
G	= Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	**DPAK−3 6.10x6.54x2.28, 2.29P**	**PAGE 1 OF 1**

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Üretici parça numarasını yazın; stok ve fiyatı hemen görün.

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Entegreden kapasitöre tüm elektronik komponent kategorileri.

Kategorilere göz atın

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Aradığınız üreticinin ürünlerini tek sayfada inceleyin.

Üreticileri görün

Toplu alım ve teklif

Listede olmayan ya da yüksek adetli parçalar için teklif isteyin.

Teklif isteyin

www.entegreci.com | **destek@entegreci.com** | **0850 305 90 34**

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